

Features

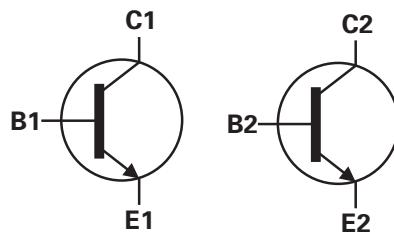
- $BV_{CEO} > 60V$
- $I_C = 1A$ high Continuous Collector Current
- $I_{CM} = 2A$ Peak Pulse Current
- $R_{CE(sat)} = 100m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage $V_{CE(sat)} < 250mV$ @ 1A
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

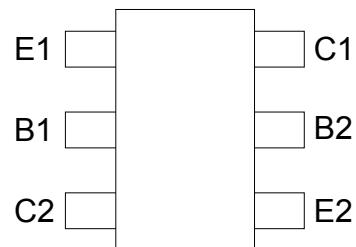
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.015 grams (approximate)



Top View



Device Symbol


 Top View
 Pin-Out

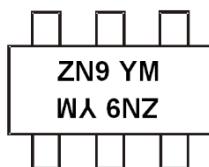
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS4160DS-7	ZN9	7	8	3,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information



ZN9 = Product Type Marking Code

YM = Date Code Marking

Y = Year ex: A = 2013

M = Month ex: 9 = September

Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019	2020				
Code	A	B	C	D	E	F	G	H				
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings – Q1 & Q2 Common (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	5	V
Continuous Collector Current	I_C	1	A
Peak Pulse Collector Current	I_{CM}	2	A
Base current	I_B	300	mA
Peak Pulse Base current	I_{BM}	1	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P_D	0.7	W mW/°C
		5.6	
		0.9	
		7.2	
		1.1	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	8.8	°C/W
		1.1	
		8.8	
		1.7	
		13.6	
Thermal Resistance, Junction to Lead	$R_{\theta JL}$	179	
Operating and Storage Temperature Range	T_J, T_{STG}	139	
		113	
		113	
		73	

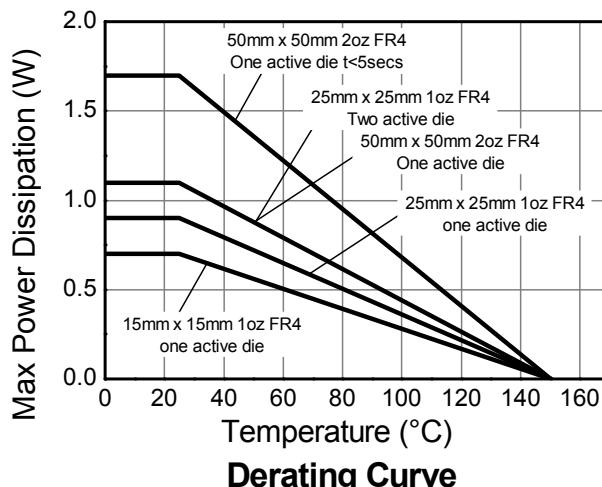
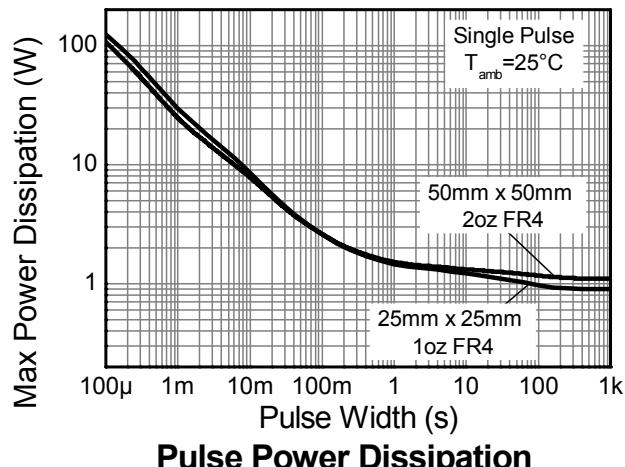
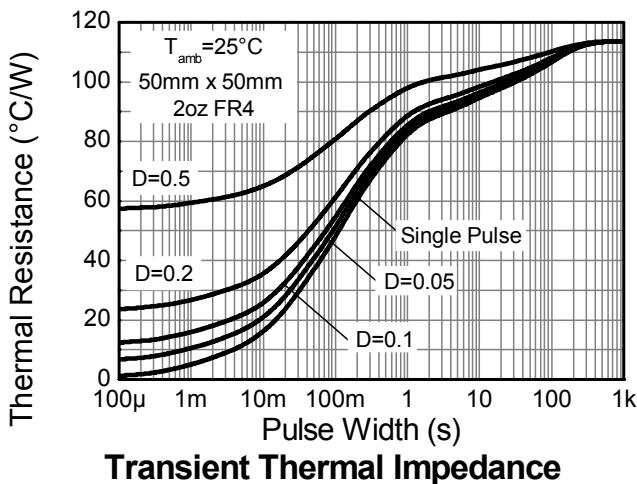
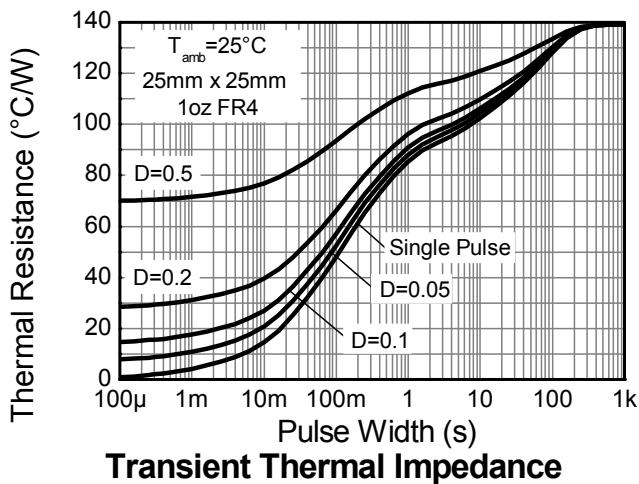
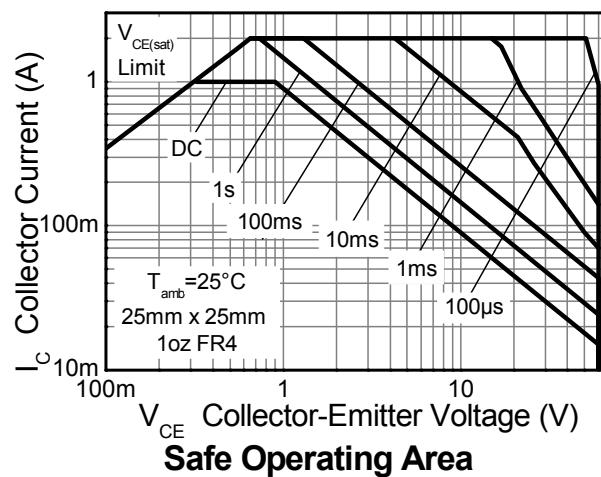
ESD Ratings (Note 12)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:

5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
7. Same as note (5), except the device is mounted on 50mm x 50mm 2oz copper.
8. Same as note (7), except the device is measured at $t < 5$ seconds.
9. One active die operating with the collector attached to the heatsink.
10. Two active dice running at equal power with heatsink split 50% to each collector.
11. Thermal resistance from junction to solder-point (at the end of the collector lead).
12. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information



Electrical Characteristics - Q1 & Q2 common (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	80	—	—	V	I _C = 100µA
Collector-Emitter Breakdown Voltage (Note 13)	BV _{CEO}	60	—	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	—	V	I _E = 100µA
Collector-Base Cutoff Current	I _{CBO}	—	—	100	nA	V _{CB} = 60V, I _E = 0A
		—	—	50	µA	V _{CB} = 60V, I _E = 0A, T _J = +150°C
Collector-Emitter Cutoff Current	I _{CES}	—	—	100	nA	V _{CES} = 60V, V _{BE} = 0V
Emitter-Base Cutoff Current	I _{EBO}	—	—	100	nA	V _{EB} = 5V, I _C = 0A
DC Current Gain (Note 13)	h _{FE}	250	380	—	—	I _C = 1mA, V _{CE} = 5V
		200	420	—	—	I _C = 500mA, V _{CE} = 5V
		100	380	—	—	I _C = 1A, V _{CE} = 5V
Collector-Emitter Saturation Voltage (Note 13)	V _{CE(sat)}	—	60	110	—	I _C = 100mA, I _B = 1mA
		—	70	140	mV	I _C = 500mA, I _B = 50mA
		—	100	250	—	I _C = 1A, I _B = 100mA
Equivalent On-Resistance	R _{CE(sat)}	—	100	250	mΩ	I _C = 1A, I _B = 100mA
Base-Emitter Saturation Voltage (Note 13)	V _{BE(sat)}	—	940	1100	mV	I _C = 1A, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 13)	V _{BE(on)}	—	780	900	mV	I _C = 1A, V _{CE} = 5V
Output Capacitance	C _{obo}	—	5.5	10	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	150	220	—	MHz	V _{CE} = 10V, I _C = 50mA f = 100MHz
Turn-On Time	t _{on}	—	63	—	ns	V _{CC} = 10V, I _C = 0.5A I _{B1} = -I _{B2} = 25mA
Delay Time	t _d	—	33	—	ns	
Rise Time	t _r	—	30	—	ns	
Turn-Off Time	t _{off}	—	420	—	ns	
Storage Time	t _s	—	380	—	ns	
Fall Time	t _f	—	40	—	ns	

Notes: 13. Measured under pulsed conditions. Pulse width ≤ 300 µs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

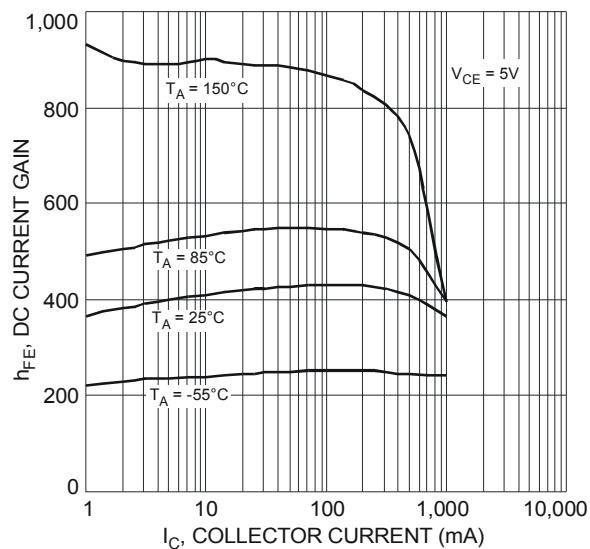


Fig. 5 Typical DC Current Gain vs. Collector Current

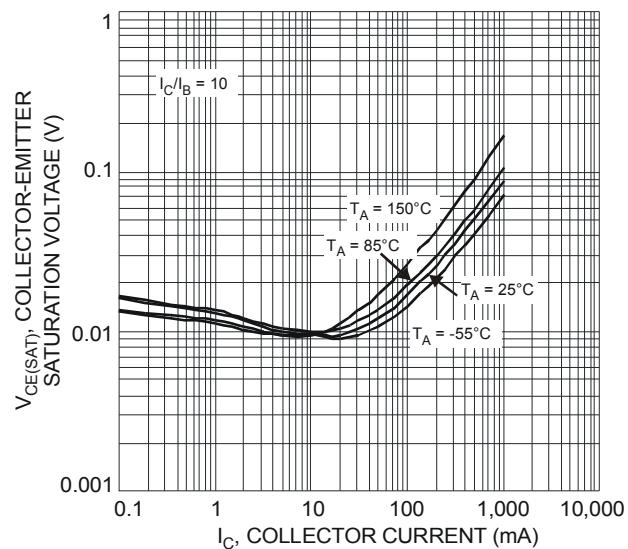


Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

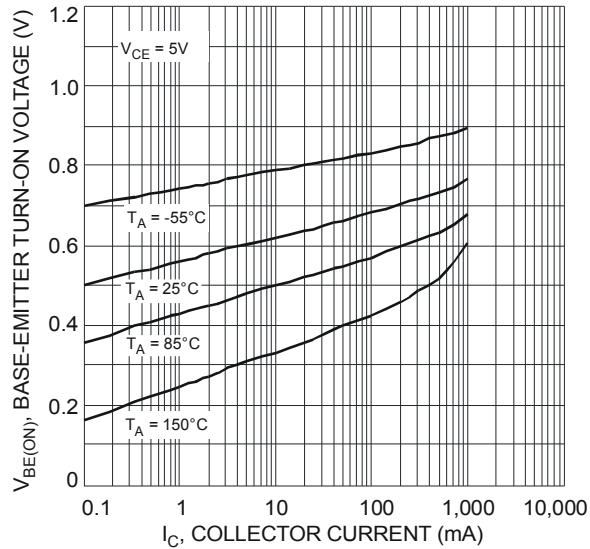


Fig. 7 Typical Base-Emitter Turn-On Voltage vs. Collector Current

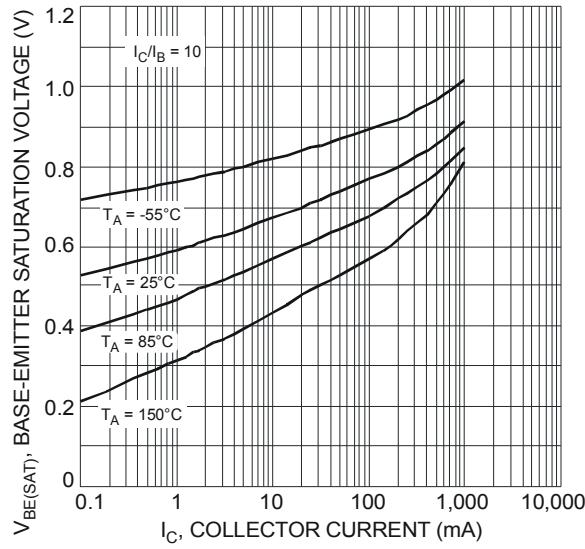


Fig. 8 Typical Base-Emitter Saturation Voltage vs. Collector Current

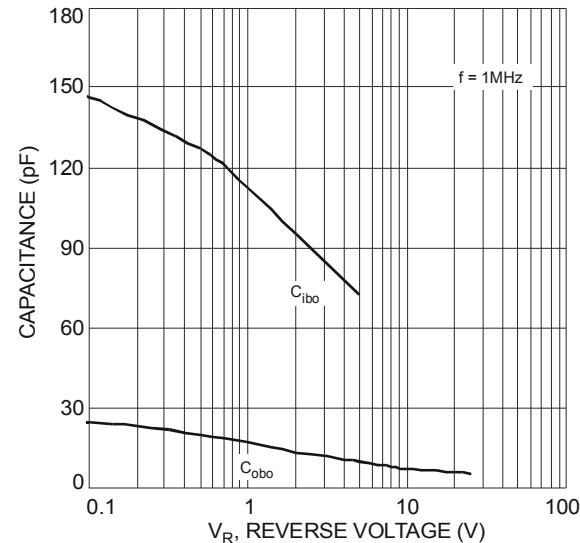
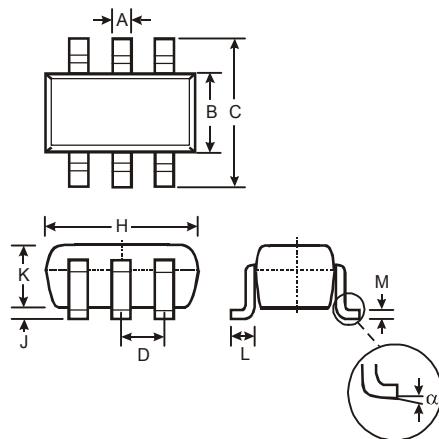


Fig. 9 Typical Capacitance Characteristics

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

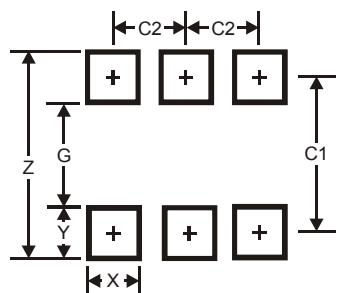


SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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